Silicon P Channel Power MOS FET High Speed Power Switching

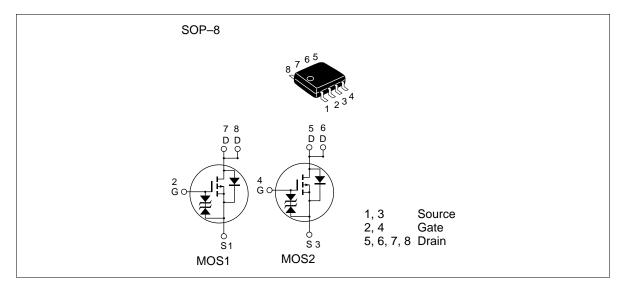
HITACHI

ADE-208-471 D (Z) 5th. Edition February 1999

Features

- Low on-resistance
- Capable of 4 V gate drive
- Low drive current
- High density mounting

Outline





Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	- 30	V	
Gate to source voltage	V _{GSS}	± 20	V	
Drain current	I _D	- 4.5	А	
Drain peak current	Note1 D(pulse)	- 36	A	
Body-drain diode reverse drain current	I _{DR}	- 4.5	A	
Channel dissipation	Pch Note2	2	W	
Channel dissipation	Pch Note3	3	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	– 55 to + 150	٥C	

Note: 1. $PW \le 10\mu s$, duty cycle $\le 1 \%$

2. 1 Drive operation : When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s

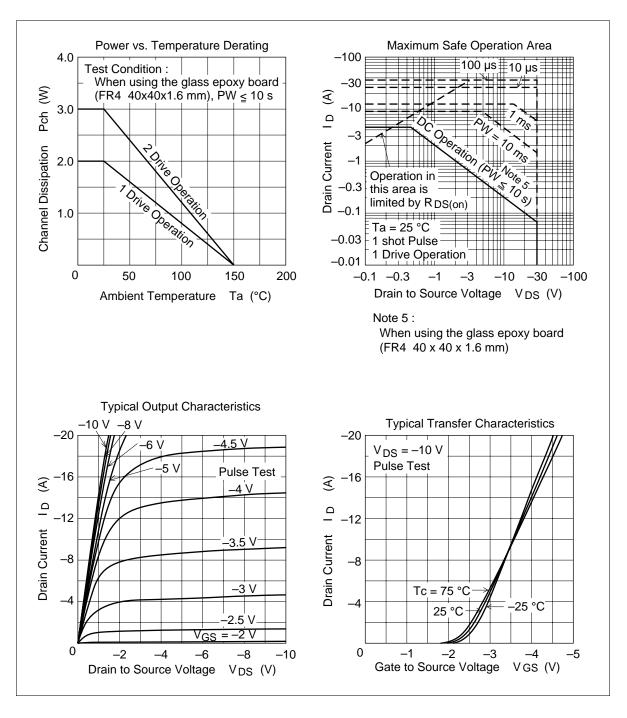
3. 2 Drive operation : When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s

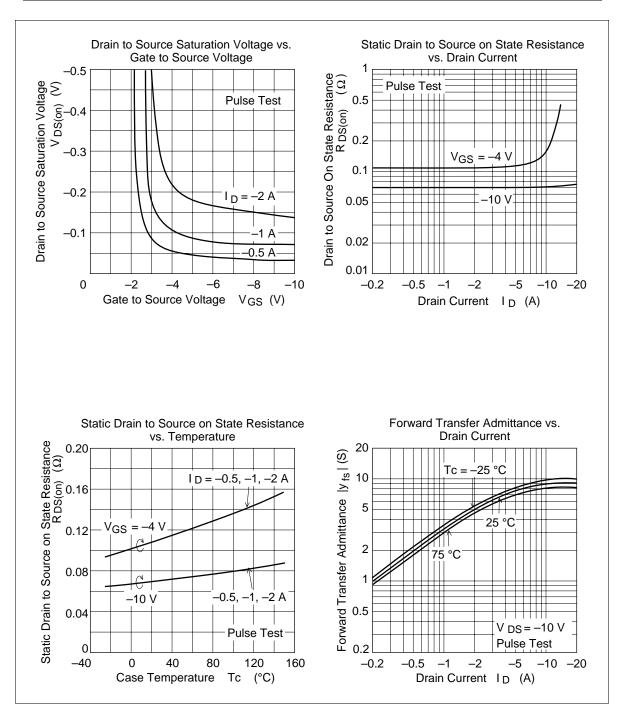
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	-30	_	_	V	$I_{\rm D} = -10$ mA, $V_{\rm GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	—	_	±10	μA	$V_{GS} = \pm 16 \text{ V}, \text{ V}_{DS} = 0$
Zero gate voltege drain current	I _{DSS}	_	_	-10	μA	$V_{\rm DS} = -30$ V, $V_{\rm GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	-1.0	_	-2.5	V	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$
Static drain to source on state	$R_{DS(on)}$	_	0.07	0.09	Ω	$I_{\rm D} = -3$ A, $V_{\rm GS} = -10$ V ^{Note4}
resistance	$R_{DS(on)}$	_	0.11	0.18	Ω	$I_{\rm D} = -3$ A, $V_{\rm GS} = -4$ V ^{Note4}
Forward transfer admittance	y _{fs}	4	6	_	S	$I_{\rm D} = -3$ A, $V_{\rm DS} = -10$ V ^{Note4}
Input capacitance	Ciss	_	660	_	pF	V _{DS} = - 10 V
Output capacitance	Coss	_	440	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	140	_	pF	f = 1MHz
Turn-on delay time	t _{d(on)}	_	24	_	ns	$V_{\rm GS} = -4$ V, $I_{\rm D} = -3$ A
Rise time	t,	_	165	_	ns	$V_{DD} \cong -10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	_	35	_	ns	_
Fall time	t _f	_	70	_	ns	_
Body-drain diode forward voltage	V_{DF}	_	-0.9	-1.4	V	$IF = -4.5 \text{ A}, V_{GS} = 0^{Note4}$
Body–drain diode reverse recovery time	t _{rr}		60		ns	$\label{eq:IF} \begin{array}{l} IF=-4.5\;A,\;V_{_{\mathrm{GS}}}=0\\ diF/\;dt\;=20\;A/\mus \end{array}$

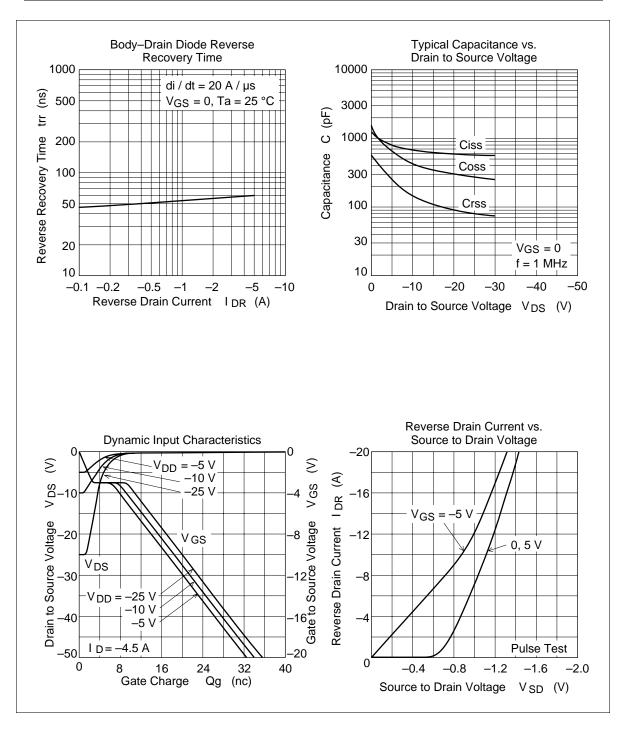
Electrical Characteristics (Ta = 25°C)

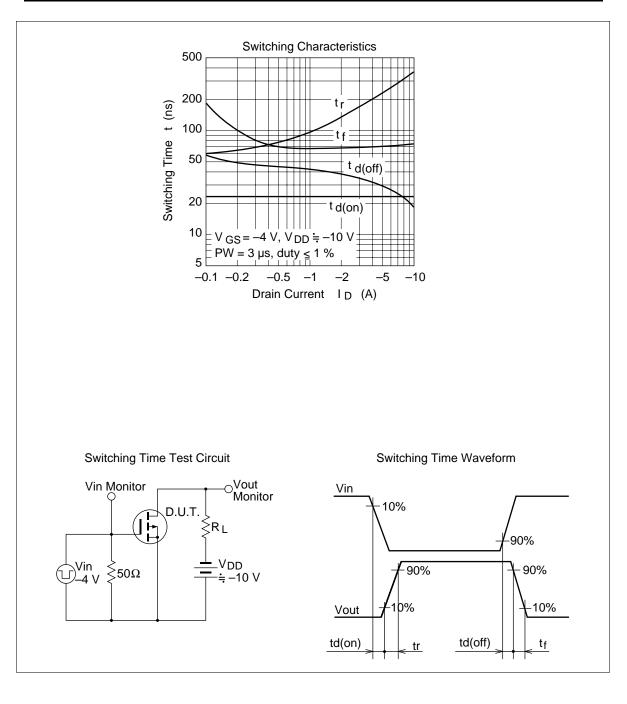
Note: 4. Pulse test

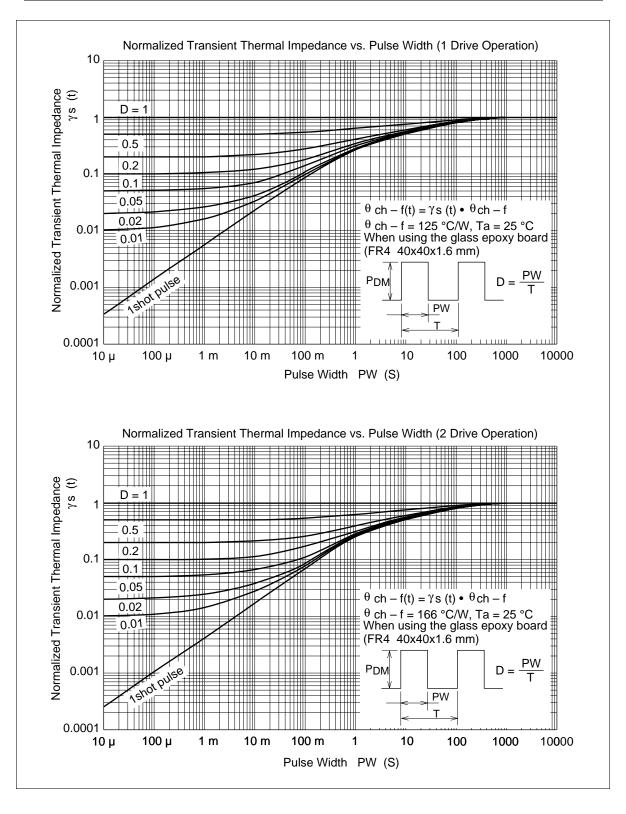
Main Characteristics





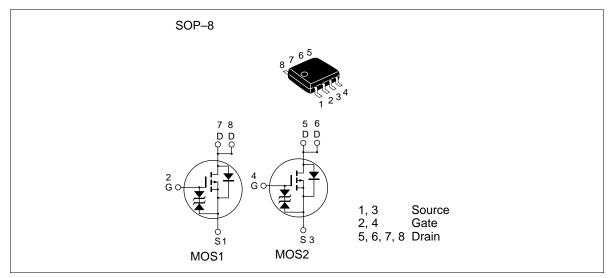






Package Dimensions

Unit: mm



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